



# SPECIFICATION

- Supplier : Samsung electro-mechanics
- Product : Multi-layer Ceramic Capacitor

- Samsung P/N : [CL10C561JB8NFNC](#)
- Description : CAP, 560pF, 50V, ±5%, C0G, 0603

## A. Samsung Part Number

**CL 10 C 561 J B 8 N F N C**  
 ① ② ③ ④ ⑤ ⑥ ⑦ ⑧ ⑨ ⑩ ⑪

|                                |                                       |  |  |                 |                          |                               |                 |  |  |  |  |  |  |  |
|--------------------------------|---------------------------------------|--|--|-----------------|--------------------------|-------------------------------|-----------------|--|--|--|--|--|--|--|
| ① <b>Series</b>                | Samsung Multi-layer Ceramic Capacitor |  |  |                 |                          |                               |                 |  |  |  |  |  |  |  |
| ② <b>Size</b>                  | 0603 (inch code)                      |  |  | L: 1.6 ± 0.1 mm |                          |                               | W: 0.8 ± 0.1 mm |  |  |  |  |  |  |  |
| ③ <b>Dielectric</b>            | C0G                                   |  |  |                 | ⑧ <b>Inner electrode</b> | Ni                            |                 |  |  |  |  |  |  |  |
| ④ <b>Capacitance</b>           | 560 pF                                |  |  |                 | ⑨ <b>Termination</b>     | Cu                            |                 |  |  |  |  |  |  |  |
| ⑤ <b>Capacitance tolerance</b> | ±5 %                                  |  |  |                 | ⑩ <b>Plating</b>         | Sn 100% (Pb Free)             |                 |  |  |  |  |  |  |  |
| ⑥ <b>Rated Voltage</b>         | 50 V                                  |  |  |                 | ⑪ <b>Product</b>         | Normal                        |                 |  |  |  |  |  |  |  |
| ⑦ <b>Thickness</b>             | 0.8 ± 0.1 mm                          |  |  |                 | ⑫ <b>Special</b>         | Product for POWER application |                 |  |  |  |  |  |  |  |
|                                |                                       |  |  |                 | ⑬ <b>Packaging</b>       | Cardboard Type, 7" reel       |                 |  |  |  |  |  |  |  |

## B. Samsung Reliability Test and Judgement condition

|   | Performance  | Test condition   |
|---|--|--|
| <b>Capacitance</b>                      | Within specified tolerance   | 1MHz±10% 0.5~5Vrms   |
| <b>Q</b>                                | 1000 min   |  |
| <b>Insulation Resistance</b>            | 10,000Mohm or 500Mohm·μF<br>Whichever is Smaller   | Rated Voltage 60~120 sec.  |
| <b>Appearance</b>                       | No abnormal exterior appearance  | Microscope (×10)   |
| <b>Withstanding Voltage</b>             | No dielectric breakdown or mechanical breakdown  | 300% of the rated voltage  |
| <b>Temperature Characterisitcs</b>      | C0G<br>(From -55 °C to 125 °C, Capacitance change shoud be within ±30PPM/°C)                     |  |
| <b>Adhesive Strength of Termination</b> | No peeling shall be occur on the terminal electrode  | 500g·F, for 10±1 sec.  |
| <b>Bending Strength</b>                 | Capacitance change :<br>within ±5% or ±0.5pF whichever is larger                                 | Bending to the limit (1mm)<br>with 1.0mm/sec.  |
| <b>Solderability</b>                    | More than 75% of terminal surface is to be soldered newly  | SnAg3.0Cu0.5 solder<br>245±5 °C, 3±0.3sec.<br>(preheating : 80~120 °C for 10~30sec.) |
| <b>Resistance to Soldering heat</b>     | Capacitance change :<br>within ±2.5% or ±0.25pF whichever is larger<br>Tan δ, IR : initial spec. | Solder pot : 270±5 °C, 10±1sec.  |

|                                    | Performance   | Test condition  |
|------------------------------------|---|---|
| <b>Vibration Test</b>              | Capacitance change :<br>within $\pm 2.5\%$ or $\pm 0.25\text{pF}$ whichever is larger<br>Tan $\delta$ , IR : initial spec.  | Amplitude : 1.5mm<br>From 10Hz to 55Hz (return : 1min.)<br>2hours $\times$ 3 direction (x, y, z)  |
| <b>Moisture Resistance</b>         | Capacitance change :<br>within $\pm 7.5\%$ or $\pm 0.75\text{pF}$ whichever is larger<br>Q : 200 min<br>IR : 500Mohm or $25\text{Mohm} \cdot \mu\text{F}$<br>Whichever is Smaller | With rated voltage<br>40 $\pm 2^\circ\text{C}$ , 90~95%RH, 500+12/-0hrs   |
| <b>High Temperature Resistance</b> | Capacitance change :<br>within $\pm 3\%$ or $\pm 0.3\text{pF}$ whichever is larger<br>Q : 350 min<br>IR : 1000Mohm or $50\text{Mohm} \cdot \mu\text{F}$<br>Whichever is Smaller   | With 200% of the rated voltage<br>Max. operating temperature<br>1000+48/-0hrs   |
| <b>Temperature Cycling</b>         | Capacitance change :<br>within $\pm 2.5\%$ or $\pm 0.25\text{pF}$ whichever is larger<br>Tan $\delta$ , IR : initial spec.  | 1 cycle condition<br>Min. operating temperature $\rightarrow 25^\circ\text{C}$<br>$\rightarrow$ Max. operating temperature $\rightarrow 25^\circ\text{C}$<br><br>5 cycle test |

#### C. Recommended Soldering method :

Reflow ( Reflow Peak Temperature : 260 $\pm 0/-5^\circ\text{C}$ , 10sec. Max )

\* For the more detail Specification, Please refer to the Samsung MLCC catalogue.